L Number	Hits	Search Text	DB	Time stamp
1	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:49
2	0	6060714.pn. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:49
3	0	6060714.pn. and (common adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/03/13 15:50
-	0	capacitor and transistor and (planarization adj layer) and (conformal adj passvation adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:10
-	0	capacitor and transistor and (planarization adj layer) and (conformal adj passivation adj layer)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 15:55
-	1	capacitor and transistor and (planarization adj layer) and (conformal with (passivation adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 15:55
-	1	capacitor and transistor and (planarization adj layer) and (conformal same (passivation adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:11
-	1	capacitor and transistor and (planarization adj layer) and imager and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:12
-	12	capacitor and transistor and (planarization adj layer) and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:24
-	940	capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:24
-	225	(storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/23 16:25
-	0	438/240,155,200,239,256,279 393,399.ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:19
-	0	257/295,312.ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:23
-	5	438/240,155,200,239,256,279,393,399.ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:55
-	5	438/240,155,200,239,256,279,393,394,395,396,397,398,399.ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:57
-	7	438/240,155,200,239,256,279,393,394,395,396,397,398,399.ccls. and (capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 11:57
-	8	257/295,296,297,298,299,300,301,302,303,304,305,306,307,308,309,310,311,312.ccls. and capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:42

–	0	250/370.09,580,214.1,ccls. and capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:21
–	0	250/370.09,580,214.1,ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:45
–	52	250/370.09,580,214.1.ccls. and capacitor and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:46
–	1	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:46
–	16	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
–	1	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and (conformal same passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
–	0	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and (conformal same passivation) and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:54
–	15	250/370.09,580,214.1.ccls. and capacitor and transistor and imager and passivation and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:55
–	0	250/370.09,580,214.1.ccls. and (storage adj capacitor) and transistor and imager and passivation and source and drain and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 12:56
–	10	250/370.09,580,214.1.ccls. and (storage adj capacitor) and transistor and imager and passivation and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:40
–	0	TW-540128-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
–	0	TW-0000540128-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
–	0	TW-5401280000-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:45
–	2	6362041.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:48
–	2	20030111740.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:50
–	2	6340638.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:20
–	2	6184121.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 14:53
–	2	5198694.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:07

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–	0	200340107687.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:07
–	2	20030107687.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:08
–	0	KR-220058794-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:09
–	0	KR-220258794-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:10
–	0	KR-200258794-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:10
–	1	KR-2002058794-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:12
–	1	KR-2002004267-$.did.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:12
–	2	6051876.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:23
–	2	5688709.PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:47
–	0	5198694.PN. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:49
–	0	5198694.PN. and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2003/12/24 15:49
–	0	6060714.pn. and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:12
–	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:13
–	0	6060714.pn. and (drain same data)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:13
–	0	438/240,241,155,200,239,256,279 393,399.ccls. and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; DERWENT	2004/02/17 12:20
–	0	438/240,241,155,200,239,256,279 393,399.ccls. and (storage adj capacitor) and transistor	USPAT; US-PGPUB; EPO; DERWENT	2004/02/17 12:20
–	0	250/370.09,580,214.1,ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:32
–	4434	257/295,296,297,298,299,300,301,302,303,304,305,306,307,308,309,310,311,312,31 and (capacitor) and transistor	USPAT; US-PGPUB; EPO; DERWENT	2004/02/17 12:28

-	14	257/295,296,297,298,299,300,301,302,303,304,306,307,308,309,310,311,312,31 and (capacitor) and transistor and x-ray and detector	USPAT; US-PGPUB; EPO; JPO; DERWENT	12:29
-	4	257/295,296,297,298,299,300,301,302,303,304,306,307,308,309,310,311,312,31 and (capacitor) and transistor and (x-ray same detector)	USPAT; US-PGPUB; EPO; JPO; DERWENT	12:29
-	0	250/59,370.09,580,214.1,ccls. and capacitor and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:33
-	0	250/59,370.09,580,214.1,ccls. and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:34
-	150	250/59,370.09,580,214.1.ccls. and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:34
-	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47
-	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:35
-	25	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:40
-	0	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarazation	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:42
-	2	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:42
-	2	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and planarization	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:44
-	1	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and conformal	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47
-	20	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and imager and @ad<20020712 and data	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:47
-	10	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and (data adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:48
-	3	250/59,370.09,580,214.1.ccls. and imager and (storage adj capacitor) and transistor and (data adj line) and (gate adj line)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 12:49
-	0	10367756.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/17 15:44
-	2	6020590.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:58
-	2	6060714.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:59

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		2	6124606.pn.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/19 11:59